

## SINGLE 2-INPUT OR GATE

### PRELIMINARY DATA

- HIGH SPEED:  $t_{PD} = 3.8 \text{ ns}$  (TYP.) at  $V_{CC} = 5V$
- LOW POWER DISSIPATION:  
 $I_{CC} = 2 \mu A$  (MAX.) at  $T_A = 25^\circ C$
- HIGH NOISE IMMUNITY:  
 $V_{NIH} = V_{NIL} = 28\% V_{CC}$  (MIN.)
- POWER DOWN PROTECTION ON INPUTS
- SYMMETRICAL OUTPUT IMPEDANCE:  
 $|I_{OH}| = I_{OL} = 8 \text{ mA}$  (MIN)
- BALANCED PROPAGATION DELAYS:  
 $t_{PLH} \cong t_{PHL}$
- OPERATING VOLTAGE RANGE:  
 $V_{CC}$  (OPR) = 2V to 5.5V
- IMPROVED LATCH-UP IMMUNITY

### DESCRIPTION

The 74V1G32 is an advanced high-speed CMOS SINGLE 2-INPUT OR GATE fabricated with sub-micron silicon gate and double-layer metal wiring  $C^2$ MOS technology. It has similar high speed performance of equivalent Bipolar Schottky TTL combined with true CMOS low power dissipation.



**S**  
(SOT23-5L)

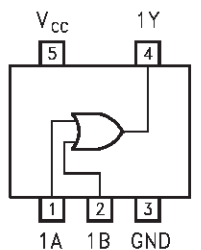
**ORDER CODES:**  
74V1G32S

The internal circuit is composed of 2 stages including buffer output, which provide high noise immunity and stable output.

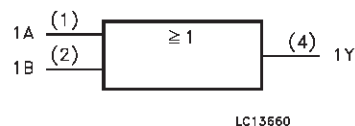
Power down protection is provided on all inputs and 0 to 7V can be accepted on inputs with no regard to the supply voltage. This device can be used to interface 5V to 3V.

All inputs and outputs are equipped with protection circuits against static discharge, giving them 2KV ESD immunity and transient excess voltage.

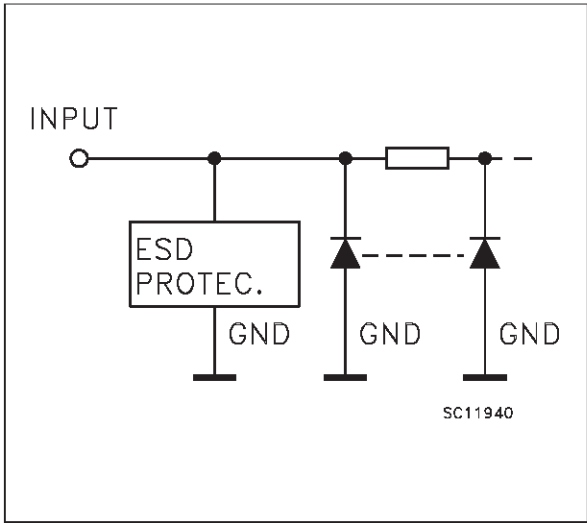
### PIN CONNECTION AND IEC LOGIC SYMBOLS



SC12290



INPUT EQUIVALENT CIRCUIT



PIN DESCRIPTION

| PIN No | SYMBOL          | NAME AND FUNCTION       |
|--------|-----------------|-------------------------|
| 1      | 1A              | Data Input              |
| 2      | 1B              | Data Input              |
| 4      | 1Y              | Data Output             |
| 5      | GND             | Ground (0V)             |
| 3      | V <sub>CC</sub> | Positive Supply Voltage |

TRUTH TABLE

| A | B | Y |
|---|---|---|
| L | L | L |
| L | H | H |
| H | L | H |
| H | H | H |

ABSOLUTE MAXIMUM RATINGS

| Symbol                              | Parameter                            | Value                         | Unit |
|-------------------------------------|--------------------------------------|-------------------------------|------|
| V <sub>CC</sub>                     | Supply Voltage                       | -0.5 to +7.0                  | V    |
| V <sub>I</sub>                      | DC Input Voltage                     | -0.5 to +7.0                  | V    |
| V <sub>O</sub>                      | DC Output Voltage                    | -0.5 to V <sub>CC</sub> + 0.5 | V    |
| I <sub>IK</sub>                     | DC Input Diode Current               | - 20                          | mA   |
| I <sub>OK</sub>                     | DC Output Diode Current              | ± 20                          | mA   |
| I <sub>O</sub>                      | DC Output Current                    | ± 25                          | mA   |
| I <sub>CC</sub> or I <sub>GND</sub> | DC V <sub>CC</sub> or Ground Current | ± 50                          | mA   |
| T <sub>stg</sub>                    | Storage Temperature                  | -65 to +150                   | °C   |
| T <sub>L</sub>                      | Lead Temperature (10 sec)            | 260                           | °C   |

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

RECOMMENDED OPERATING CONDITIONS

| Symbol          | Parameter                                                                                              | Value                | Unit         |
|-----------------|--------------------------------------------------------------------------------------------------------|----------------------|--------------|
| V <sub>CC</sub> | Supply Voltage                                                                                         | 2.0 to 5.5           | V            |
| V <sub>I</sub>  | Input Voltage                                                                                          | 0 to 5.5             | V            |
| V <sub>O</sub>  | Output Voltage                                                                                         | 0 to V <sub>CC</sub> | V            |
| T <sub>op</sub> | Operating Temperature                                                                                  | -40 to +85           | °C           |
| dt/dv           | Input Rise and Fall Time (see note 1) (V <sub>CC</sub> = 3.3 ± 0.3V)<br>(V <sub>CC</sub> = 5.0 ± 0.5V) | 0 to 100<br>0 to 20  | ns/V<br>ns/V |

1) V<sub>IN</sub> from 30% to 70% of V<sub>CC</sub>

## DC SPECIFICATIONS

| Symbol          | Parameter                 | Test Conditions        |                                                                          |                        | Value |                    |                    |                    |      | Unit |
|-----------------|---------------------------|------------------------|--------------------------------------------------------------------------|------------------------|-------|--------------------|--------------------|--------------------|------|------|
|                 |                           | V <sub>CC</sub><br>(V) |                                                                          | T <sub>A</sub> = 25 °C |       |                    | -40 to 85 °C       |                    |      |      |
|                 |                           |                        |                                                                          | Min.                   | Typ.  | Max.               | Min.               | Max.               |      |      |
| V <sub>IH</sub> | High Level Input Voltage  | 2.0                    |                                                                          | 1.5                    |       |                    | 1.5                |                    | V    |      |
|                 |                           | 3.0 to 5.5             |                                                                          | 0.7V <sub>CC</sub>     |       |                    | 0.7V <sub>CC</sub> |                    |      |      |
| V <sub>IL</sub> | Low Level Input Voltage   | 2.0                    |                                                                          |                        |       | 0.5                |                    | 0.5                | V    |      |
|                 |                           | 3.0 to 5.5             |                                                                          |                        |       | 0.3V <sub>CC</sub> |                    | 0.3V <sub>CC</sub> |      |      |
| V <sub>OH</sub> | High Level Output Voltage | 2.0                    | V <sub>I</sub> <sup>(*)</sup> =<br>V <sub>IH</sub> or<br>V <sub>IL</sub> | I <sub>O</sub> =-50 μA | 1.9   | 2.0                |                    | 1.9                |      | V    |
|                 |                           | 3.0                    |                                                                          | I <sub>O</sub> =-50 μA | 2.9   | 3.0                |                    | 2.9                |      |      |
|                 |                           | 4.5                    |                                                                          | I <sub>O</sub> =-50 μA | 4.4   | 4.5                |                    | 4.4                |      |      |
|                 |                           | 3.0                    |                                                                          | I <sub>O</sub> =-4 mA  | 2.58  |                    |                    | 2.48               |      |      |
|                 |                           | 4.5                    |                                                                          | I <sub>O</sub> =-8 mA  | 3.94  |                    |                    | 3.8                |      |      |
| V <sub>OL</sub> | Low Level Output Voltage  | 2.0                    | V <sub>I</sub> <sup>(*)</sup> =<br>V <sub>IH</sub> or<br>V <sub>IL</sub> | I <sub>O</sub> =50 μA  |       | 0.0                | 0.1                |                    | 0.1  | V    |
|                 |                           | 3.0                    |                                                                          | I <sub>O</sub> =50 μA  |       | 0.0                | 0.1                |                    | 0.1  |      |
|                 |                           | 4.5                    |                                                                          | I <sub>O</sub> =50 μA  |       | 0.0                | 0.1                |                    | 0.1  |      |
|                 |                           | 3.0                    |                                                                          | I <sub>O</sub> =4 mA   |       |                    | 0.36               |                    | 0.44 |      |
|                 |                           | 4.5                    |                                                                          | I <sub>O</sub> =8 mA   |       |                    | 0.36               |                    | 0.44 |      |
| I <sub>I</sub>  | Input Leakage Current     | 0 to 5.5               | V <sub>I</sub> = 5.5V or GND                                             |                        |       |                    | ±0.1               |                    | ±1.0 | μA   |
| I <sub>CC</sub> | Quiescent Supply Current  | 5.5                    | V <sub>I</sub> = V <sub>CC</sub> or GND                                  |                        |       |                    | 1                  |                    | 10   | μA   |

(\*) All outputs loaded.

AC ELECTRICAL CHARACTERISTICS (Input t<sub>r</sub> = t<sub>f</sub> = 3 ns)

| Symbol           | Parameter              | Test Condition         |                        | Value                  |      |      |              |      | Unit |
|------------------|------------------------|------------------------|------------------------|------------------------|------|------|--------------|------|------|
|                  |                        | V <sub>CC</sub><br>(V) |                        | T <sub>A</sub> = 25 °C |      |      | -40 to 85 °C |      |      |
|                  |                        |                        |                        | Min.                   | Typ. | Max. | Min.         | Max. |      |
| t <sub>PLH</sub> | Propagation Delay Time | 3.3 <sup>(*)</sup>     | C <sub>L</sub> = 15 pF |                        | 5.5  | 8.0  | 1.0          | 9.5  | ns   |
| t <sub>PHL</sub> |                        | 3.3 <sup>(*)</sup>     | C <sub>L</sub> = 50 pF |                        | 8.0  | 11.5 | 1.0          | 13.0 |      |
|                  |                        | 5.0 <sup>(**)</sup>    | C <sub>L</sub> = 15 pF |                        | 3.8  | 5.5  | 1.0          | 6.5  |      |
|                  |                        | 5.0 <sup>(**)</sup>    | C <sub>L</sub> = 50 pF |                        | 5.3  | 7.5  | 1.0          | 8.5  |      |

(\*) Voltage range is 3.3V ± 0.3V

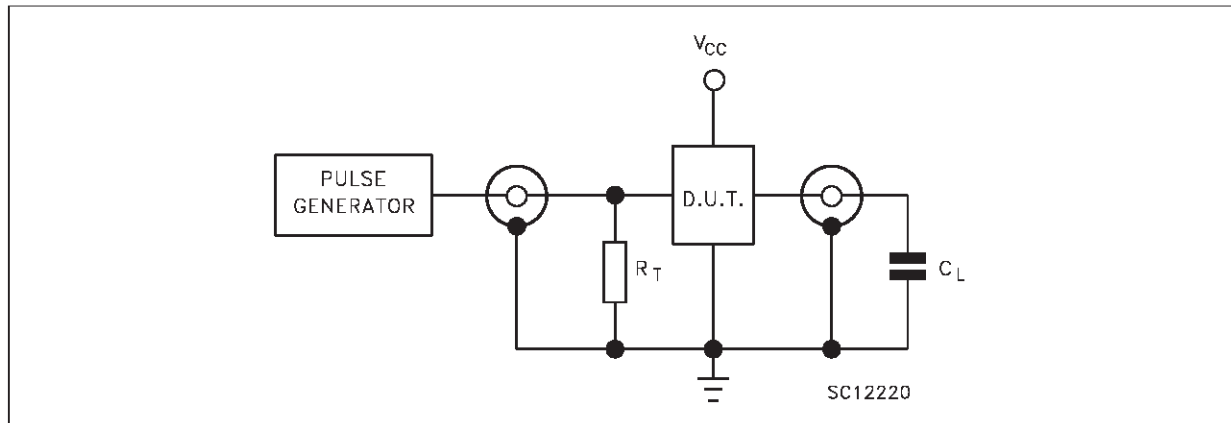
(\*\*) Voltage range is 5V ± 0.5V

## CAPACITIVE CHARACTERISTICS

| Symbol          | Parameter                              | Test Conditions | Value                  |      |      |              |    | Unit |
|-----------------|----------------------------------------|-----------------|------------------------|------|------|--------------|----|------|
|                 |                                        |                 | T <sub>A</sub> = 25 °C |      |      | -40 to 85 °C |    |      |
|                 |                                        | Min.            | Typ.                   | Max. | Min. | Max.         |    |      |
| C <sub>IN</sub> | Input Capacitance                      |                 |                        | 4    | 10   |              | 10 | pF   |
| C <sub>PD</sub> | Power Dissipation Capacitance (note 1) |                 |                        | 14   |      |              |    | pF   |

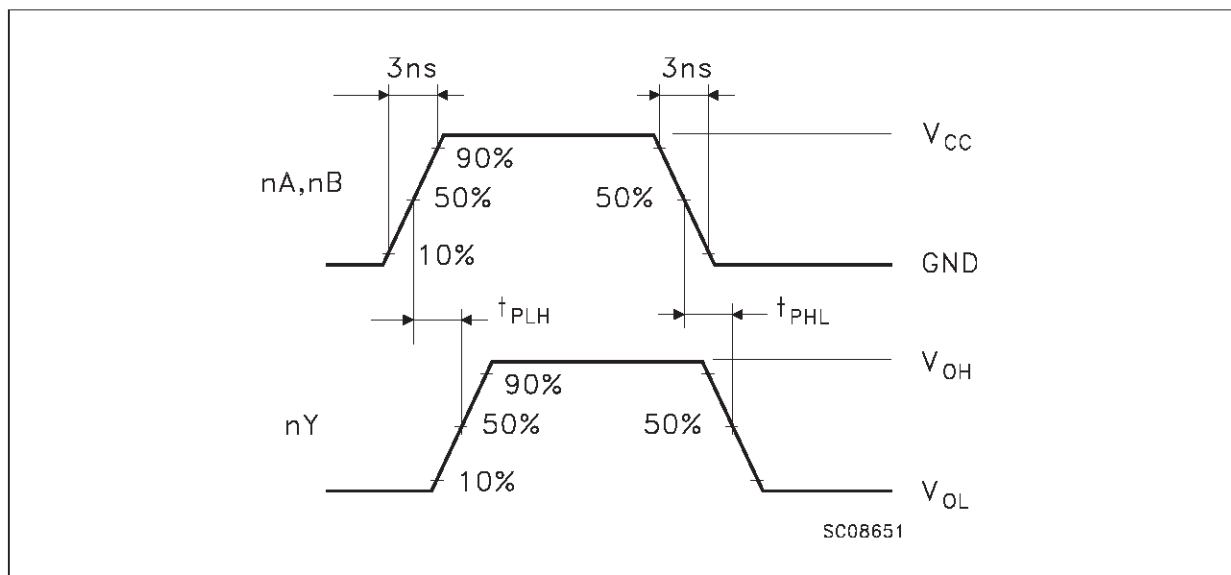
1) C<sub>PD</sub> is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation. I<sub>CC(opr)</sub> = C<sub>PD</sub> • V<sub>CC</sub> • f<sub>IN</sub> + I<sub>CC</sub>/4 (per Gate)

## TEST CIRCUIT



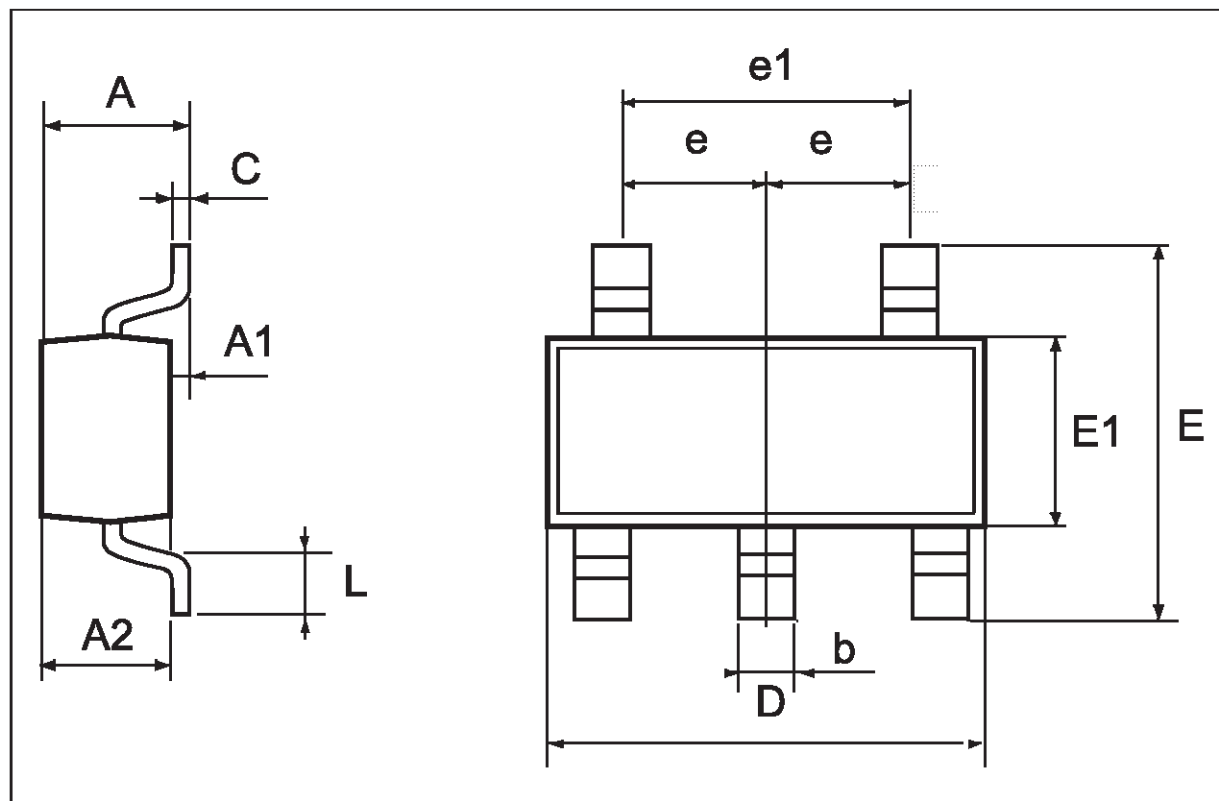
$C_L = 15/50$  pF or equivalent (includes jig and probe capacitance)

$R_T = Z_{OUT}$  of pulse generator (typically  $50\Omega$ )

WAVEFORM: PROPAGATION DELAYS ( $f=1\text{MHz}$ ; 50% duty cycle)

## SOT23-5L MECHANICAL DATA

| DIM. | mm   |      |      | mils  |      |       |
|------|------|------|------|-------|------|-------|
|      | MIN. | TYP. | MAX. | MIN.  | TYP. | MAX.  |
| A    | 0.90 |      | 1.45 | 35.4  |      | 57.1  |
| A1   | 0.00 |      | 0.15 | 0.0   |      | 5.9   |
| A2   | 0.90 |      | 1.30 | 35.4  |      | 51.2  |
| b    | 0.35 |      | 0.50 | 13.7  |      | 19.7  |
| C    | 0.09 |      | 0.20 | 3.5   |      | 7.8   |
| D    | 2.80 |      | 3.00 | 110.2 |      | 118.1 |
| E    | 2.60 |      | 3.00 | 102.3 |      | 118.1 |
| E1   | 1.50 |      | 1.75 | 59.0  |      | 68.8  |
| L    | 0.35 |      | 0.55 | 13.7  |      | 21.6  |
| e    |      | 0.95 |      |       | 37.4 |       |
| e1   |      | 1.9  |      |       | 74.8 |       |



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